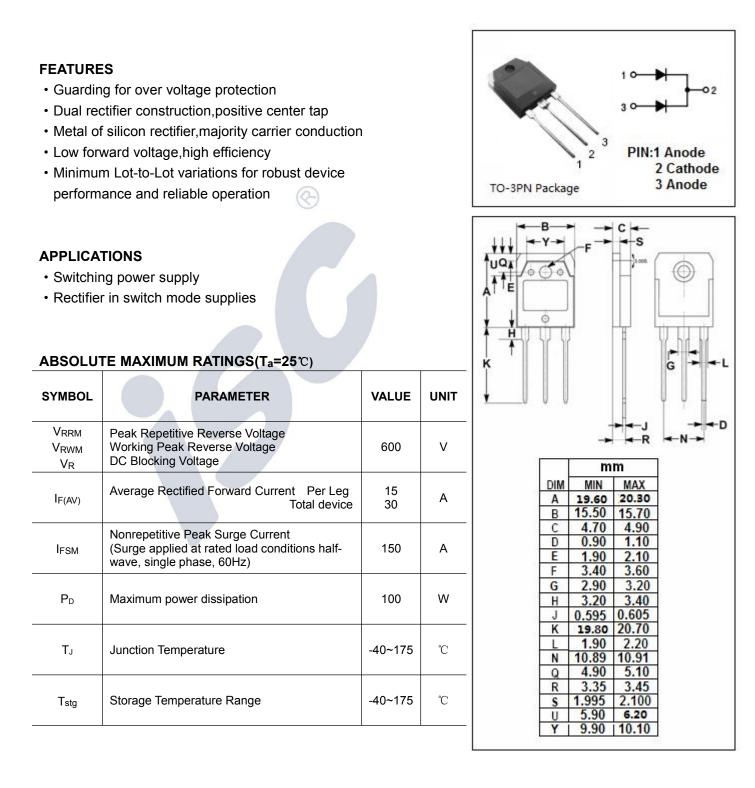


isc

Ultrafast Rectifier

INCHANGE SEMICONDUCTOR

MUR3060PT





INCHANGE SEMICONDUCTOR

Fast Recovery Rectifier

MUR3060PT

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.5	°C /W

ELECTRICAL CHARACTERISTICS(Ta=25℃) (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V _{F*}	Maximum Instantaneous Forward Voltage	IF= 15A ;Tj=25℃ IF= 15A ;Tj=150℃	1.5 1.2	V
I _{R*}	Maximum Instantaneous Reverse Current	V _R = V _{RWM;} Tj=25℃ V _R = V _{RWM;} Tj=150℃	10 1000	μA
t _{rr}	Maximum Reverse Recovery Time	IF =1A;	60	ns

*:Pulse Test:Pulse width=300us,duty cycle≤2.0%

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.